

# PJA3401A

## 30V P-Channel Enhancement Mode MOSFET

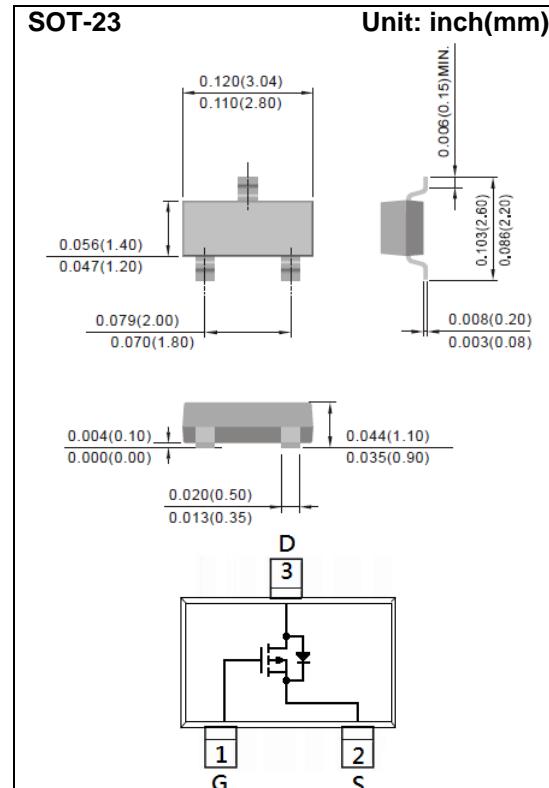
Voltage      -30 V      Current      -3.6A

### Features

- R<sub>DS(ON)</sub> , V<sub>GS</sub>@-10V, I<sub>D</sub>@-3.6A<54mΩ
- R<sub>DS(ON)</sub> , V<sub>GS</sub>@-4.5V, I<sub>D</sub>@-2.3A<63mΩ
- R<sub>DS(ON)</sub> , V<sub>GS</sub>@-2.5V, I<sub>D</sub>@-1.4A<86mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std.. (Halogen Free)

### Mechanical Data

- Case : SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V <sub>DS</sub>	-30	V
Gate-Source Voltage	V <sub>GS</sub>	±12	V
Continuous Drain Current	I <sub>D</sub>	-3.6	A
Pulsed Drain Current	I <sub>DM</sub>	-14.4	A
Power Dissipation	T <sub>a</sub> =25°C	1.25	W
	Derate above 25°C	10	mW/°C
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55~150	°C
Typical Thermal Resistance - Junction to Ambient <sup>(Note 3)</sup>	R <sub>θJA</sub>	100	°C/W

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### Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=-250\mu\text{A}$	-30	-	-	V
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=-250\mu\text{A}$	-0.5	-1	-1.3	V
Drain-Source On-State Resistance	$R_{\text{DS(on)}}$	$V_{\text{GS}}=-10\text{V}, I_{\text{D}}=-3.6\text{A}$	-	45	54	$\text{m}\Omega$
		$V_{\text{GS}}=-4.5\text{V}, I_{\text{D}}=-2.3\text{A}$	-	52	63	
		$V_{\text{GS}}=-2.5\text{V}, I_{\text{D}}=-1.4\text{A}$	-	71	86	
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}}=-30\text{V}, V_{\text{GS}}=0\text{V}$	-	-	-1	$\mu\text{A}$
Gate-Source Leakage Current	$I_{\text{GSS}}$	$V_{\text{GS}}=\pm 12\text{V}, V_{\text{DS}}=0\text{V}$	-	-	$\pm 100$	nA
<b>Dynamic</b> <sup>(Note 5)</sup>						
Total Gate Charge	$Q_g$	$V_{\text{DS}}=-15\text{V}, I_{\text{D}}=-3.6\text{A}, V_{\text{GS}}=-10\text{V}^{(\text{Note 1,2})}$	-	19	-	nC
Gate-Source Charge	$Q_{\text{gs}}$		-	2.0	-	
Gate-Drain Charge	$Q_{\text{gd}}$		-	2.2	-	
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=-15\text{V}, V_{\text{GS}}=0\text{V}, f=1.0\text{MHZ}$	-	994	-	pF
Output Capacitance	$C_{\text{oss}}$		-	78	-	
Reverse Transfer Capacitance	$C_{\text{rss}}$		-	58	-	
Turn-On Delay Time	$t_{\text{d(on)}}$	$V_{\text{DD}}=-15\text{V}, I_{\text{D}}=-3.6\text{A}, V_{\text{GS}}=-10\text{V}, R_{\text{G}}=6\Omega^{(\text{Note 1,2})}$	-	4.6	-	ns
Turn-On Rise Time	$t_{\text{r}}$		-	22	-	
Turn-Off Delay Time	$t_{\text{d(off)}}$		-	41	-	
Turn-Off Fall Time	$t_{\text{f}}$		-	25	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_{\text{s}}$	---	-	-	-1.5	A
Diode Forward Voltage	$V_{\text{SD}}$	$I_{\text{s}}=-1.0\text{A}, V_{\text{GS}}=0\text{V}$	-	-0.79	-1.2	V

#### NOTES :

1. Pulse width $\leq 300\mu\text{s}$ , Duty cycle $\leq 2\%$ .
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\text{OJA}}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.

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## TYPICAL CHARACTERISTIC CURVES

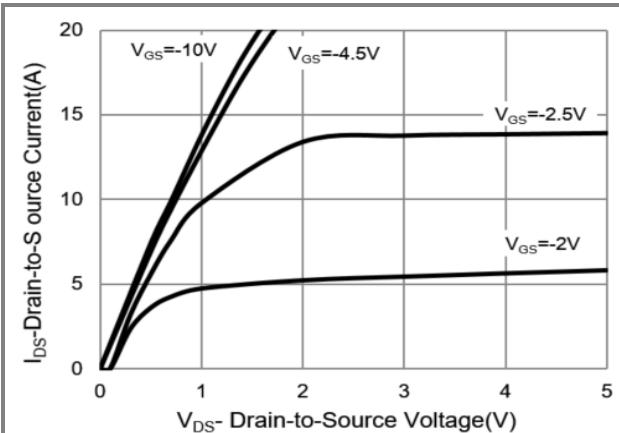


Fig.1 On-Region Characteristics

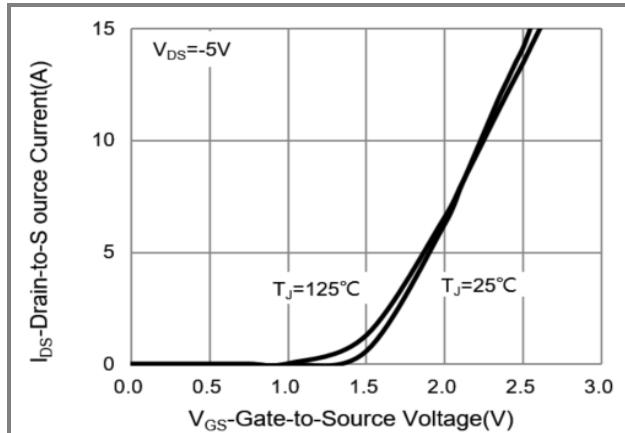


Fig.2 Transfer Characteristics

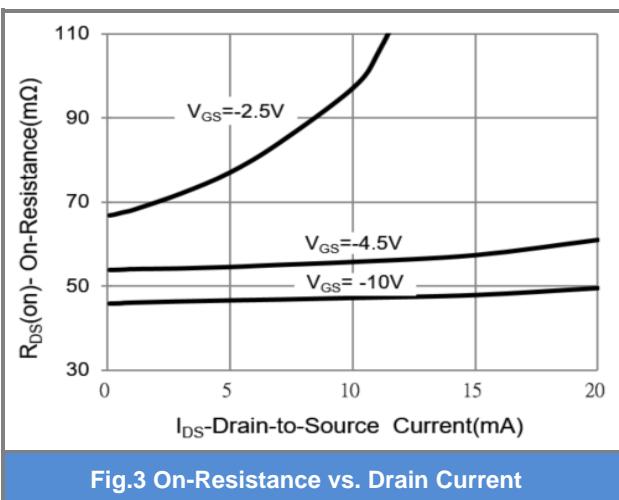


Fig.3 On-Resistance vs. Drain Current

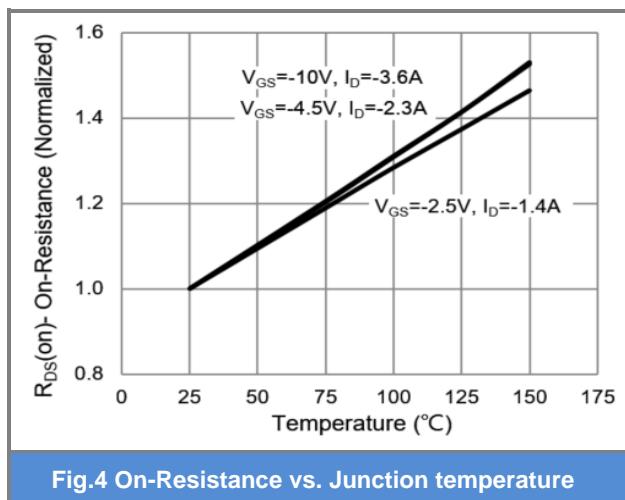


Fig.4 On-Resistance vs. Junction temperature

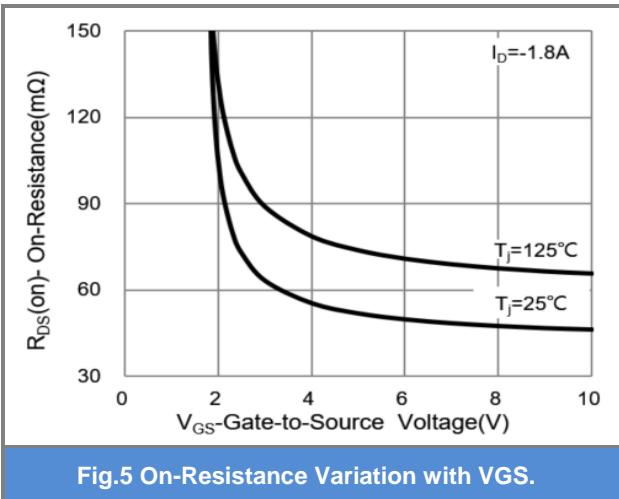


Fig.5 On-Resistance Variation with VGS.

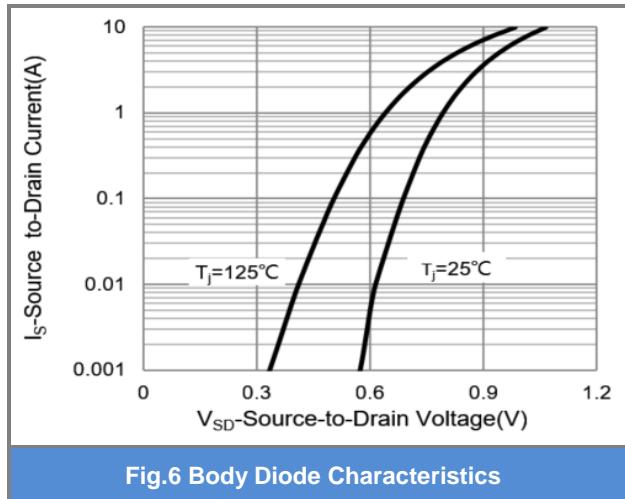


Fig.6 Body Diode Characteristics

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## TYPICAL CHARACTERISTIC CURVES

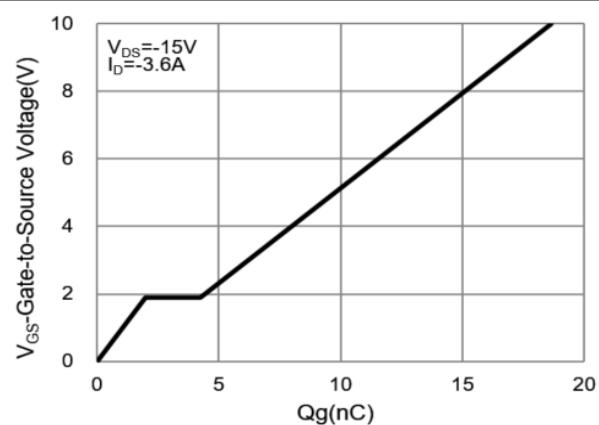


Fig.7 Gate-Charge Characteristics

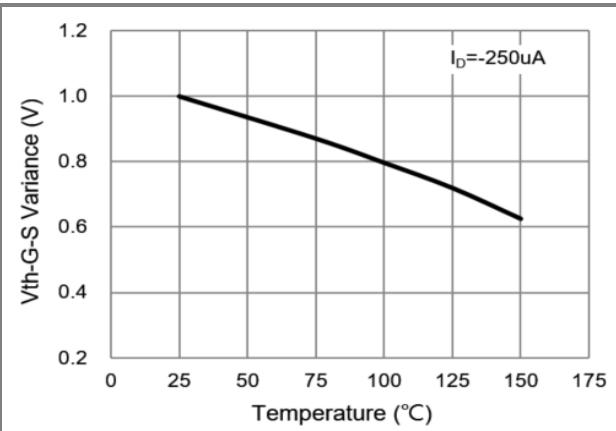


Fig.8 Threshold Voltage Variation with Temperature.

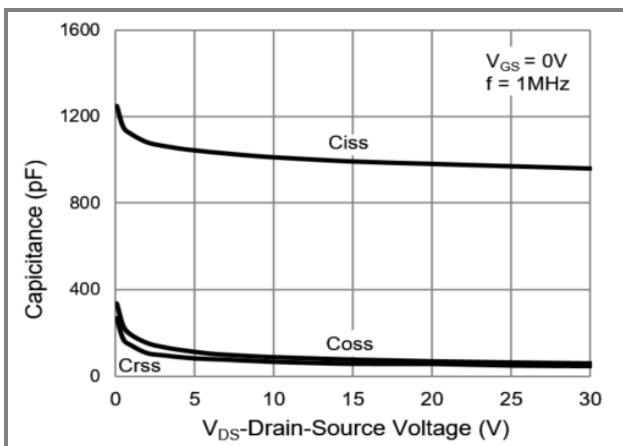


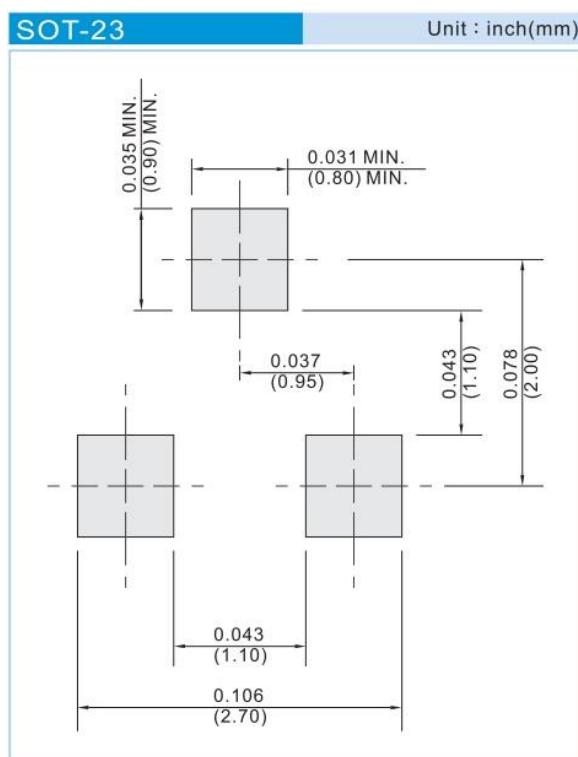
Fig.9 Capacitance vs. Drain-Source Voltage.

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## Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJA3401A	SOT-23	3K pcs / 7" reel	A1A

## Mounting Pad Layout



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